Electric permittivity of the vacuum in a strong constant electric field

Hidetoshi Taya

(Keio U.)

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<u>This talk</u>

Discuss the electric permittivity ϵ of the vacuum in a strong constant electric field



- ϵ is no longer a const. $\epsilon = \epsilon(\overline{E})$ due to the vacuum polarization
- many studies since the early days, ^[Heisenberg-Euler (1936)] [Toll 1952] [Klein-Nigam (1964)] [Baier-Breitenlohner (1967)] ... Review: [King-Heinzl (2015)] [Ejlli et al. (PVLAS) (2020)] [Fedotov et al. (2023)] ...
 but is still worthwhile to be investigated ⇒ 3 motivations

(1) The current understanding is limited to weak/slow regime

The most famous formula = based on Euler-Heisenberg Lagrangian

$$\mathcal{D} = -\frac{\partial \mathcal{L}_{\rm EH}}{\partial \mathcal{E}} \implies \epsilon = \frac{\alpha}{45\pi} \left(\frac{e\bar{E}}{m^2}\right)^2 \times \begin{cases} 6 \ (\parallel) \\ 2 \ (\perp) \end{cases}$$
[Baier-Breitenlohner (1967)]

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[Baier-Breitenlohner (1967)]

cf. [Heinzl-Schroder (2006)]

cf. [King-Heinzl-Blackburn (2023)]

<u>Problem 1: Valid only in the weak limit $e\overline{E} \ll m^2$ </u>

power corrections could be included $(e\overline{E})^n$, but

- is factorially divergent \Rightarrow does not necessarily improve the formula
- non-pert. factor like $e^{1/e\overline{E}}$ can never be included

<u>Problem 2: Valid only in the slow limit $\omega \ll m$ </u>

- not possible to discuss ω dependence
- the physics must be different above the pair-production threshold $\omega > 2m$

Problem 3: Neglecting the imaginary part Im \mathcal{L}_{EH}

- ϵ (in the coordinate space) must be real, so one must set Im $\mathcal{L}_{Euler-Heisenberg}$
- \Rightarrow pair production and "non-equilibrium-ness" of E field are completely dismissed

Q: What happens if I go beyond those limitations?







(2) As a signature of non-trivial QED vacuum structure in E field

The QED vacuum (= the Dirac sea) has a non-trivial electron dist. in an E field, which can leave observable imprints

QED vacuum at $\overline{E} = 0$

← positive energy states

← mass gap ~ 2m

← Dirac sea

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Q: What happens to the electric permittivity ?

Note: The motivation (1) (in particular, going beyond $\omega \ll m$) is important to achieve this

(3) Pursue analogy between strong-field QED and semicond. phys

- Ground-state structure of semicond. = The QED vacuum
 - ⇒ the QED vacuum should response against external field in a similar way to a semiconductor and vice versa

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- Ground-state structure of semicond. = The QED vacuum
 - ⇒ the QED vacuum should response against external field in a similar way to a semiconductor and vice versa
- Nontrivial oscillating change in ε (i.e., motivation (2)) has already been observed more than 50 yrs ago in semicond. physics !
 (⇒ the Franz-Keldysh effect and electroreflectance) [Franz (1958)] [Keldysh (1958)]



Q: Natural to expect this change in QED. Is this analogy true?

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II. Theory Linear response theory based on in-in formalism of QFT

III. Results will give positive statements to the motivations (1) - (3)

IV. Summary

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Setup: QED under a constant strong field \overline{E} + a weak spatially homo. probe $\mathcal{E}(t)$

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Step 1: Definitions of \mathcal{D} and ϵ

• Total flux
$$D = E + P(\overline{E}, \mathcal{E}) = E + P_0(\overline{E}) + P_1(\overline{E})\mathcal{E} + \cdots$$

 $\overrightarrow{E} + \mathcal{E} = \overline{E} + P_0(\overline{E}) + (1 + P_1(\overline{E}))\mathcal{E} + \cdots \Rightarrow \epsilon = 1 + P_1(\overline{E})$

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Step 2: Calculate P₁

• Ampere law:
$$-\dot{P} = J = \langle 0; \operatorname{in} | \bar{\psi}(\bar{E}, \mathcal{E}) \gamma^{\mu} \psi(\bar{E}, \mathcal{E}) | 0; \operatorname{in} \rangle$$

 $= \langle 0; \operatorname{in} | \bar{\psi}_0(\bar{E}) \gamma^{\mu} \psi_0(\bar{E}) | 0; \operatorname{in} \rangle$
 $+ \langle 0; \operatorname{in} | \bar{\psi}_1(\bar{E}) \gamma^{\mu} \psi_0(\bar{E}) + \bar{\psi}_0(\bar{E}) \gamma^{\mu} \psi_1(\bar{E}) | 0; \operatorname{in} \rangle \times \mathcal{E} + \mathcal{O}(\mathcal{E}^2)$

- Not in-out amplitude, but in-in ! cf. [Copinger-Fukushima-Shi (2018)]
 - ⇒ crucial when pair creating (or in non-equil.): $|0; out\rangle = |0; in\rangle + (pair states like |e^+e^-; in\rangle)$
- Diagrammatically, evaluate

Detail 1: Loop diagram \Rightarrow UV divergent \Rightarrow use Kramers-Kronig relation

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$$[Toll (1960)] [Heinzl, Schroeder (2006)] [Borysov et al. (2022)]$$
Causality $\Rightarrow \operatorname{Re} \epsilon(\omega) = \frac{1}{\pi} \operatorname{P.V.} \int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega' - \omega} \operatorname{Im} \epsilon(\omega')$
P sufficient to calculate the imaginary part (same approach has been adopted in semicond.)
[Aspnes(1967)] Im $\epsilon(\omega')$

Detail 2: Im ϵ is directly related to the (dynamically-assisted) Schwinger effect

- Electromagnetism tells us: Im ϵ is related to the dielectric energy loss See, e.g., textbook by Landau-Lefshitz
- Energy loss of probe due to the pair prod.
- Microscopically, the dielectric energy loss should be caused by the pair prod.

$$\frac{\mathrm{d}U_1}{\mathrm{d}t} = \mathcal{E}\frac{\mathrm{d}\mathcal{D}}{\mathrm{d}t} = \frac{1}{2}\omega\mathcal{E}^2 \operatorname{Im} \epsilon$$
$$\frac{\mathrm{d}U_2}{\mathrm{d}t} = \omega\frac{N(\mathcal{E}\neq 0) - N(\mathcal{E}=0)}{VT}$$
$$U_1 = U_2 \implies \frac{N(\mathcal{E}\neq 0) - N(\mathcal{E}=0)}{VT} = \frac{1}{2}\mathcal{E}^2 \operatorname{Im} \epsilon$$

 \therefore Schwinger \leftrightarrow Im $\epsilon \stackrel{\kappa}{\leftrightarrow}$ Re $\epsilon \Rightarrow \epsilon$ as an indirect sign. of Schwinger & vice versa

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<u>Results (1/3): Imaginary part of $\Delta \epsilon$ </u>



• Oscillation, as expected from the tilted vacuum



TEMR = - 191°C

- Essentially the same pattern as semi-conductor observation
- Birefringent (Im $\Delta \epsilon_{\parallel} \neq \text{Im } \Delta \epsilon_{\perp}$) but the basically the same
- Non-vanishing even at $\omega \to 0$ due to the strong-field non-perturbative effect A simple explanation: In the slow limit, the standard Schwinger formula is valid $\Rightarrow \operatorname{Im} \epsilon \propto (N_{\operatorname{Schwinger}}(\overline{\overline{E}} + \varepsilon) - N_{\operatorname{Schwinger}}(\overline{\overline{E}})) \propto (\exp\left[-\pi \frac{m^2}{e(\overline{\overline{E}} + \varepsilon)}\right] - \exp\left[-\pi \frac{m^2}{e\overline{\overline{E}}}\right]) = (\operatorname{finite}) \times \exp\left[-\pi \frac{m^2}{e\overline{\overline{E}}}\right]$

<u>Results (2/3): Real part of $\Delta \epsilon$ </u>



- Oscillation, consistent with semi-conductor
- Logarithmically divergent at $\omega \rightarrow 0$ due to the non-perturbative effect

$$\therefore \quad \operatorname{Re} \epsilon(0) = \frac{1}{\pi} \operatorname{P.V.} \int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega'} \operatorname{Im} \epsilon(\omega')$$
$$\sim \frac{1}{\pi} \int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega'} \operatorname{Im} \epsilon(0) \sim (\log \operatorname{div.}) \times \exp\left[-\pi \frac{m^2}{e\overline{E}}\right]$$



Results (3/3): Comparison w/ EH



- After the log subtraction, the result is consistent with the EH result $\Delta \epsilon_{\rm EH} = \frac{\alpha}{45\pi} \left(\frac{e\bar{E}}{m^2}\right)^2 \times \begin{cases} 6 \ (\parallel) \\ 2 \ (\perp) \end{cases}$
- Significant deviation for finite ω and/or stronger \overline{E}

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<u>Summary</u>

Discussed the electric permittivity ϵ of the vacuum in a strong constant electric field

Three motivations and my answers to them:

Motivations: (1) The current understanding is limited to weak/slow regime(2) As a signature of non-trivial QED vacuum structure in E field(3) Pursue analogy between strong-field QED and semicond. phys

Answers: (1): Succeeded with a linear response theory based on in-in formalism (2)&(3): Yes, a characteristic oscillating structure in ϵ , similarly to semicond.



Other lessons (and further comments)

• Higher frequency gives a bigger signal of ϵ (or vacuum birefringence, in general) e.g. peak at $\omega \sim 2m$: Re $\Delta \epsilon_{\parallel} \approx (-1.4 \times 10^{-4}) \times \left(\frac{I}{1 \times 10^{23} \text{ W/cm}^2}\right)^{0.19} \Rightarrow \Delta \epsilon_{\text{EH}} = O(10^{-7}) \text{ for } I = O(1 \times 10^{23} \text{ W/cm}^2)$

• Need to go beyond EH for large ω or strong $\overline{E} \Rightarrow$ implications to heavy-ion coll., magnetar, ... ? • Schwinger $\leftrightarrow \operatorname{Im} \epsilon \stackrel{\mathsf{KK}}{\leftrightarrow} \operatorname{Re} \epsilon \Rightarrow \epsilon$ as an indirect signature of Schwinger & vice versa



Peak value

Behaviors of the peaks



Numerical fit says (similar numbers for Im ϵ_{\perp} and Re $\epsilon_{\parallel,\perp}$)

$$\operatorname{Re}\Delta\epsilon_{\parallel} \approx (-1.4 \times 10^{-4}) \times \left(\frac{I}{1 \times 10^{23} \text{ W/cm}^2}\right)^{0.19}$$
 where $I = \overline{E}^2/2$ is the focused intensity

• much larger than EH e.g., $\Delta \epsilon_{\rm EH} = O(10^{-7})$ for $I = O(1 \times 10^{23} \text{ W/cm}^2)$ (PW laser)

 \Rightarrow High-frequency probe is useful to study ϵ (or vacuum birefringence, in general)

• weak E dependence $\Delta \epsilon \propto I^{\frac{1}{5} \sim \frac{1}{6}}_{-\frac{1}{6}} \Rightarrow$ the peaks of $\Delta \epsilon$ can still be large for subcritical fields

e.g., only one-order smaller $\Delta \epsilon = O(1 \times 10^{-5}) \gg \Delta \epsilon_{\rm EH}$ at GW scale